Micro-Probe's Apollo™ Vertical Probe Card

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Presentation Overview

- Introduction
- DRAM Parallel Probing Evolution
- Apollo Design Features
- Apollo Performance Features
- Conclusion
Introduction

- Brief History of Micro-Probe
- Micro-Probe’s Participation In The Evolution Of Parallel Testing
  - Epoxy Testing
    - Single Tier Epoxy Technology
    - Epoxy Shelf Technology
  - Micro-Probe’s Entry Into The Vertical Market
    - Silicon Based Technology Research/Development
    - Apollo Research, Development and Manufacturing
### DRAM Parallel Probing History

<table>
<thead>
<tr>
<th>Year</th>
<th>Device</th>
<th>Photolithography Technology</th>
<th>Parallelism Probed</th>
<th>Total Bits Probed Per Touchdown</th>
</tr>
</thead>
<tbody>
<tr>
<td>1983</td>
<td>64K</td>
<td>2.25 Micron</td>
<td>1X</td>
<td>64K</td>
</tr>
<tr>
<td>1984</td>
<td>64K</td>
<td>2.0 Micron</td>
<td>2X</td>
<td>128K</td>
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<tr>
<td>1985</td>
<td>256K</td>
<td>1.75 Micron</td>
<td>2X</td>
<td>256K</td>
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<td>1986</td>
<td>256K</td>
<td>1.5 Micron</td>
<td>2X</td>
<td>512K</td>
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<tr>
<td>1987</td>
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<td>1.25 Micron</td>
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<tr>
<td>1988</td>
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<td>2 MEG</td>
</tr>
<tr>
<td>1989</td>
<td>1MEG</td>
<td>0.9 Micron</td>
<td>4X</td>
<td>4 MEG</td>
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<tr>
<td>1990</td>
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<td>4X</td>
<td>4 MEG</td>
</tr>
<tr>
<td>1991</td>
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<td>0.60 Micron</td>
<td>4X</td>
<td>16 MEG</td>
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<tr>
<td>1992</td>
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<td>0.50 Micron</td>
<td>8X</td>
<td>32 MEG</td>
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<tr>
<td>1993</td>
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<td>2001</td>
<td>128MEG</td>
<td>0.13 Micron</td>
<td>64X</td>
<td>8192 MEG</td>
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</table>

>200,000%  95% Geometry Reduction  6,300%  >13,000,000%
DRAM Evolution Summary Since 1983:

- DRAM device bit density has increased from 64K to 128 Meg - over 200,000% increase
- DRAM photolithography geometry reduced from 2.25 micron to .13 micron technology - 95% geometry reduction
- DRAM probing parallelism increased from single site testing (1X) to 64 site testing - 6300% increase
- The total number of DRAM bits probed per touchdown increased from 64K in 1983 to 8192 Meg in 2001 - 13,000,000% increase
Apollo Component Stack-up
Apollo Cross Sectional View
Apollo Top View
Apollo Bottom View
Apollo Design Features

- Head Design
  - Innovative implementation of ceramic lower guide plate
  - Optimized probe design to assure durable, reliable performance
  - Attractive manufacturing costs and lead-times
  - 3 mil. diameter probe with .5 mil. diameter tip utilized for layouts down to 130 micron pitch
  - Development in progress to reduce pitch capability of existing head design

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Apollo Design Features (cont.)

- Head Design (cont.)
  - Precision micro-drilling technology delivers accurate probe positioning
  - Identification bit capabilities within the head
Apollo Design Features (cont.)

- Organic Interposer Design
  - Apollo Organic Flex Circuit Interposer provides sound electrical and mechanical performance
    - Electrical characteristics and impedance requirements can be tightly controlled to the DUT
    - De-coupling capacitors are installed on the interposer in close proximity to the DUT
  - Mechanical durability has proven very reliable
  - Thin, streamlined interposer design provides mechanical stack-up flexibility
Apollo Organic Interposer-Top
Apollo Organic Interposer-Top
Apollo Organic Interposer-Bottom
Apollo Design Features (cont.)

- Metal In Elastomer (MIE) Interposer to PCB Interconnect Technology
  - Economical, Simple and Reliable
  - Easily adaptable to varying design requirements
  - MIE thickness can be varied to meet an array of probe depth requirements
Apollo Performance Features

- Dependable, robust electrical and mechanical performance on the production floor
  - Very reliable contact performance between the distal (upper) end of the probe and the interposer contact pads
Apollo Performance Features (cont.)

- Limited maintenance required
  - Smooth/conical profile of the Paliney probe tip coupled with the succinct scrub action of the probe eliminates regimented card cleaning requirements
Dry brush/dry air is all that is normally necessary to keep probe tips and guide plate clean of any incidental contaminants.

- Solvents are never recommended to clean probe tips or guide plate.
- The use of abrasive substrates and Gel Pak cleaning materials found necessary on other vertical technologies have been qualified for use on the Apollo, but are not necessary under normal production conditions.
- Abrasive cleaning is recommended only after contamination build-up is not effectively resolved with dry cleaning.
The Apollo’s precise probe placement, small 12.5 micron tip diameter probe tip and concise scrub action allow semiconductor manufacturers the advantage to proceed with pad dimension reductions.
Apollo Probe Marks
Leading Competitor Probe Marks
Apollo Performance Features (cont.)

➢ The durability of the Apollo is unmatched in comparison to other multi-site vertical solutions on the market

➢ Excessive overtravel applied to the probe card is the most common cause of early card retirement
Apollo Performance Features (cont.)

- The Apollo has demonstrated the ability to withstand excessive overtravel and continue to operate in production.
- Instances have been documented of 32 site Apollo probe cards enduring maximum overtravel and continuing to operate effectively in production.
- Further design efforts are in progress to assure that Apollo probe cards have the ability to withstand maximum overtravel without incurring damage to the probe card.
Conclusion

- The Apollo Vertical Probe Card line has addressed the fundamental requirements of today’s multi-site applications:
  - Design innovation supports economical cost of ownership and dependable lead times
  - Design features provide reliable, durable performance
  - Design flexibility will provide solutions for a large spectrum of multi-site layout variances
- Micro-Probe thanks you for your attention!